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Trademarks

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1 Introduction

The TPS5124 is a dual independent synchronous buck controller. Both controllers internal to the TPS5124 operate at 180° phase shift and the input ripple is partially canceled, therefore, the required input capacitance is reduced. Other features include a separate soft-start circuit and standby control. See the [TPS5124 Dual Channel Synchronous Step-Down PWM Controller Data Sheet](#) for detail.

2 Features

This EVM is designed to operate from 12-V bus voltage. It generates two outputs: 3.3 V at 15 A and 1.5 V at 10 A.

Table 2-1. TPS5124EVM-001 Performance Summary

Parameter	Test Conditions	MIN	TYP	MAX	Units
Input voltage range		6.5	12.0	15.0	V
Operating frequency			300		kHz
Input ripple voltage (RMS)	$V_{IN} = 12\text{ V}$, $I_{OUT1} = 15\text{ A}$, $I_{OUT2} = 10\text{ A}$		92		mV
Channel 1					
Output current range	$6.5\text{ V} \leq V_{IN} \leq 15\text{ V}$	0	15	16	A
Line regulation	$6.5\text{ V} \leq V_{IN} \leq 15\text{ V}$, $I_{OUT} = 15\text{ A}$		±0.1%		
Load regulation	$1\text{ A} \leq I_{OUT} \leq 15\text{ A}$, $V_{IN} = 12\text{ V}$		±0.3%		
Load transient response voltage change	I_{OUT} rising from 0 A to 8.5 A		-160		mV _{PK}
	I_{OUT} falling from 8.5 A to 0 A		200		
Load transient response recovery time	I_{OUT} rising from 0 A to 8.5 A		80		ms
	I_{OUT} falling from 8.5 A to 0 A		120		
Loop bandwidth	$I_{OUT} = 15\text{ A}$		30		kHz
Phase margin	$I_{OUT} = 15\text{ A}$		55		°
Output ripple voltage	$I_{OUT} = 15\text{ A}$		33	66	mV _{PP}
Output rise time	$V_{IN} = 12\text{ V}$, $V_{OUT} = 3.3\text{ V}$, $I_{OUT} = 15\text{ A}$		2.85		ms
Full load efficiency	$V_{IN} = 12\text{ V}$, $V_{OUT} = 3.3\text{ V}$, $I_{OUT} = 15\text{ A}$		90.6%		
Channel 2					
Output current range	$6.5\text{ V} \leq V_{IN} \leq 15\text{ V}$	0	10	12	A
Line regulation	$6.5\text{ V} \leq V_{IN} \leq 15\text{ V}$		±0.1%		
Load regulation	$1\text{ A} \leq I_{OUT} \leq 10\text{ A}$, $V_{IN} = 12\text{ V}$		±0.3%		
Load transient response voltage change	I_{OUT} rising from 0 A to 7.5 A		-120		mV _{PK}
	I_{OUT} falling from 7.5 A to 0 A		220		
Load transient response recovery time	I_{OUT} rising from 0 A to 7.5 A		40		ms
	I_{OUT} falling from 7.5 A to 0 A		80		
Loop bandwidth	$I_{OUT} = 10\text{ A}$		23		kHz
Phase margin	$I_{OUT} = 10\text{ A}$		55		°
Output ripple voltage	$I_{OUT} = 10\text{ A}$		15	30	mV _{PP}
Output rise time	$V_{IN} = 12\text{ V}$, $V_{OUT} = 1.5\text{ V}$, $I_{OUT} = 10\text{ A}$		2.12		ms
Full load efficiency	$V_{IN} = 12\text{ V}$, $V_{OUT} = 1.53\text{ V}$, $I_{OUT} = 10\text{ A}$		85.5%		

3 Schematic

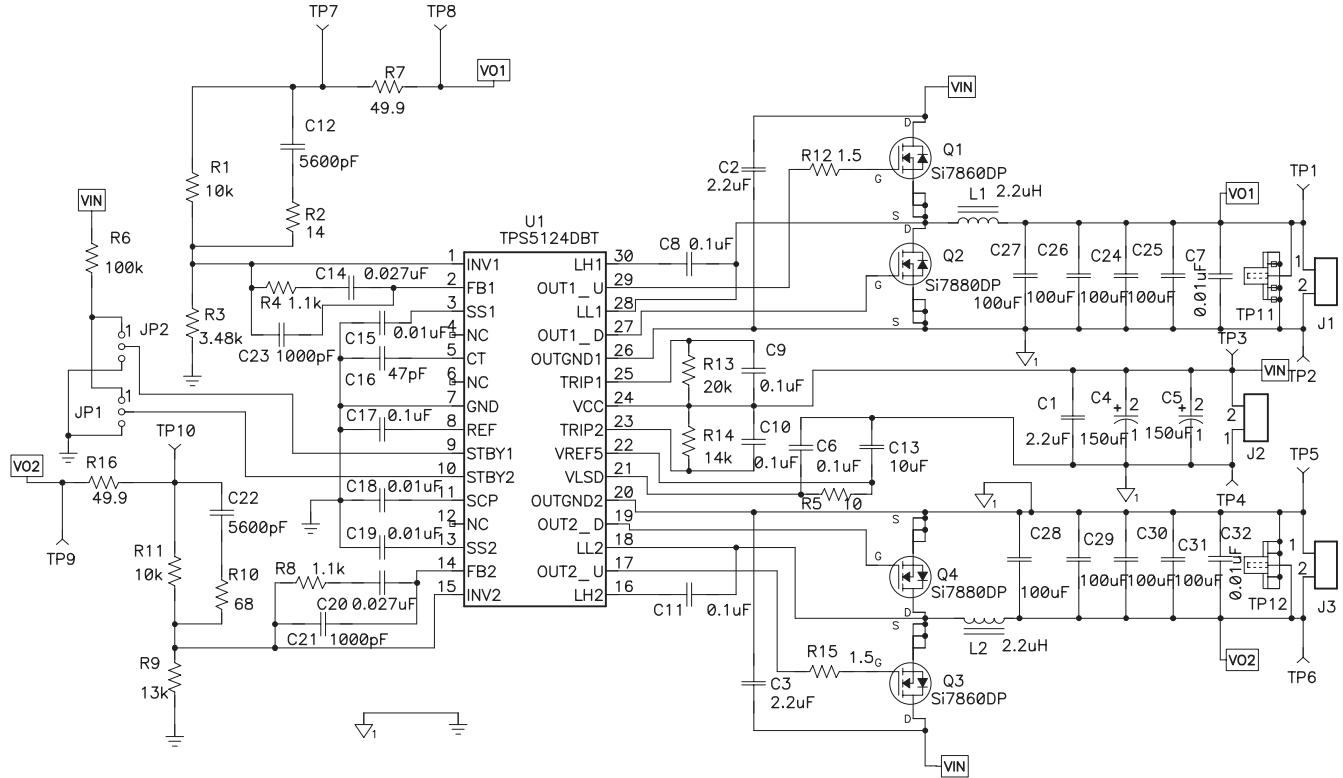


Figure 3-1. HPA053 TPS5124 Controller Schematic

4 Design Procedure

4.1 Frequency Setting

Many factors influence frequency selection. Higher switching frequency leads to smaller output inductor and capacitors, reducing the size of the converter. However, higher switching frequencies increase switching losses, and lower the efficiency of the converter. A frequency of 300 kHz is chosen for this design for reasonable efficiency and size.

Capacitor C16, which is connected from CT (pin 5) to ground, programs the oscillator frequency. A C16 value of 47 pF yields a switching frequency of 300 kHz at 25°C.

4.2 Inductance Value

The inductance value can be calculated using [Equation 1](#).

$$L = \frac{V_{OUT}}{f_{(min)} \times I_{RIPPLE}} \times \left(1 - \frac{V_{OUT}}{V_{IN(max)}} \right) \quad (1)$$

where

- I_{RIPPLE} is the ripple current flowing through the inductor.

The ripple current affects the output voltage ripple and core losses. Based on 20% ripple current and 300 kHz, the inductance value is calculated as 2.2 μ H. An off-the-shelf 2.2- μ H inductor from Vishay is chosen. The part number is IHLP-5050CE-01-2R2M01. The DCR is 7 m Ω and the DCR-related conduction loss is 1.6 W, which is about 3.3% of output power.

The same procedure is followed to choose the inductor for Channel 2. The same inductor is chosen.

4.3 Output Capacitors

The required output capacitance and its ESR can be calculated using [Equation 2](#) and [Equation 3](#).

$$C_{OUT(min)} = \frac{I_{RIPPLE}}{8 \times f \times V_{RIPPLE}} \quad (2)$$

$$ESR_{OUT} = \frac{V_{RIPPLE}}{I_{RIPPLE}} \quad (3)$$

With 1% output voltage ripple, the required minimum output capacitance is 54 μ F and its ESR should be less than 7.7 m Ω .

From the load transient point of view, the capacitance needed for 6% overshoot can be calculated using [Equation 4](#).

$$C_{OUT} = \frac{(I_{OUT(max)})^2 \times L}{(V_{OUT2})^2 - (V_{OUT1})^2} \quad (4)$$

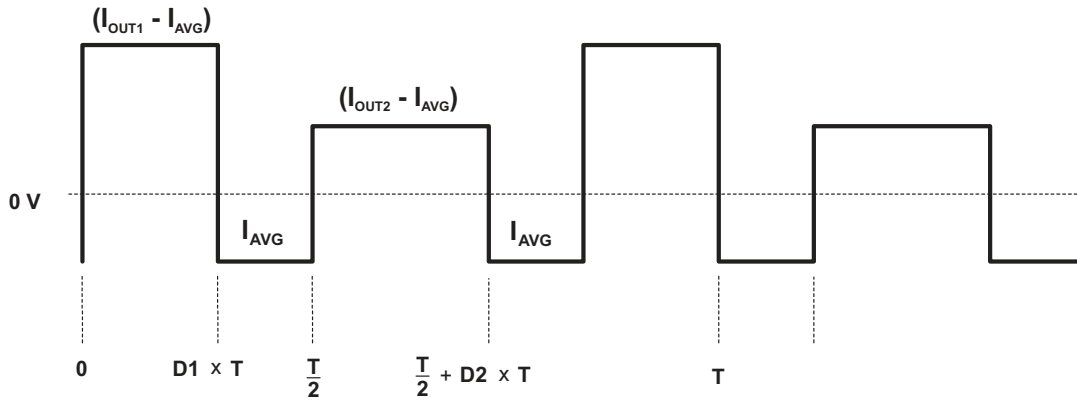
where

- V_{OUT2} is the allowed overshoot voltage.
- V_{OUT1} is the nominal operating voltage.

For 6% overshoot, the required capacitance is about 370 μ F. Four 100- μ F, 6.3-V ceramic capacitors are used. Their ESR value is 2.0 m Ω each.

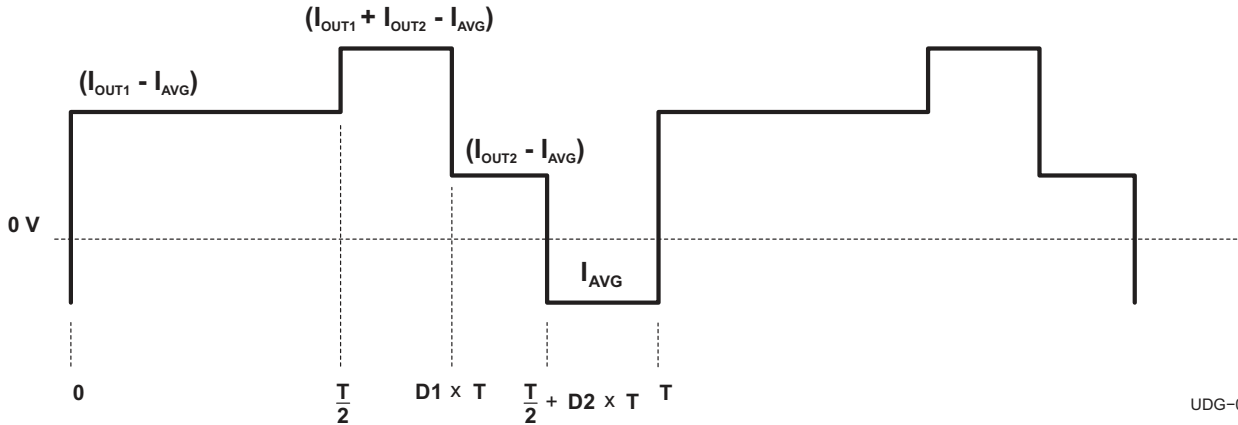
4.4 Input Capacitors

Due to the out-of-phase operation, the input current ripple is partially canceled. The total RMS current in the input capacitor is calculated as follows. This assumes the total input current goes into the input capacitor to the power ground and ignores the ripple current in the inductor.



UDG-04010

Figure 4-1. Case One ($D1 < 0.5, D2 < 0.5$)



UDG-04010

Figure 4-2. Case Two ($D2 < 0.5 < D1$)

4.4.1 Case One: $D1, D2 < 0.5$

The ripple current through the input capacitor is shown in [Figure 4-1](#) and can be calculated using [Equation 5](#).

$$I_{incapRMS} = \sqrt{\frac{1}{T} \times \left[\int_0^{D1 \times T} (I_{OUT1} - I_{AVG})^2 dt + \int_{D1 \times T}^{\frac{T}{2}} (I_{AVG})^2 dt + \int_{\frac{T}{2} + D2 \times T}^T (I_{OUT2} - I_{AVG})^2 dt + \int_{\frac{T}{2} + D2 \times T}^{\frac{T}{2}} (I_{AVG})^2 dt \right]} \quad (5)$$

$$I_{incapRMS} = \sqrt{D1 \times (I_{OUT1})^2 + D2 \times (I_{OUT2})^2 - (I_{AVG})^2} \quad (6)$$

where

- I_{AVG} is the average input current.

$$I_{AVG} = I_{OUT1} \times D1 + I_{OUT2} \times D2 \quad (7)$$

4.4.2 Case Two: $D2 < 0.5 < D1$

The ripple current through the input capacitor is shown in [Section 4.4](#) and can be calculated using [Equation 8](#).

$$\sqrt{\frac{1}{T} \times \left[\int_0^{\frac{T}{2}} (I_{OUT1} - I_{AVG})^2 dt + \int_{\frac{T}{2}}^{D1 \times T} (I_{OUT1} + I_{OUT2} - I_{AVG})^2 dt + \int_{D1 \times T}^{\frac{T}{2} + D2 \times T} (I_{OUT2} - I_{AVG})^2 dt + \int_{\frac{T}{2} + D2 \times T}^T (I_{AVG})^2 dt \right]}$$

$$I_{incapRMS} = \sqrt{D1 \times (I_{OUT1})^2 + D2 \times (I_{OUT2})^2 + (2 \times D1 - 1) \times I_{OUT1} \times I_{OUT2} - (I_{AVG})^2} \quad (9)$$

This EVM meets “Case One” criteria. The maximum input ripple current is 6.7 A at $V_{IN} = 12$ V. Two 150- μ F, 20-V special polymer capacitors from Panasonic (part number is EEFWA1D151P) are used. It can handle 3.7 A of ripple current each. The ESR value of each capacitor is 26 m Ω . So the input ripple voltage is calculated using Equation 10 and is approximately 88 mV_{RMS}.

$$I_{RIPPLE} = I_{in\text{cap}RMS} \times ESR \quad (10)$$

4.5 Compensation Design

The following compensation loop design uses Channel 1 as example, but a design for Channel 2 follows the same rules.

The TPS5124 uses voltage-mode control method. A Type III compensation network, formed by R1, R2, R4, C14, C12, and C23, is used to ensure the stability. The L-C frequency of the power stage is around 5.4 kHz and the ESR zero is at 790 KHz due to the low ESR of the ceramic capacitors. An overall crossover frequency (f_{0db}) of 30 kHz is chosen for reasonable transient response and stability. Both zeros (f_{Z1} and f_{Z2}) from the compensator are set at 2.68 kHz. The two poles (f_{P1} and f_{P2}) and are set at 150 kHz and 2 MHz. The frequency of poles and zeros are defined by the following equations.

$$f_{Z1} = \frac{1}{2\pi \times R4 \times C14} \quad (11)$$

$$f_{Z2} = \frac{1}{2\pi \times R1 \times C12} \quad (12)$$

where

- R1 >> R2 is assumed.

$$f_{P1} = \frac{1}{2\pi \times R4 \times C23} \quad (13)$$

$$f_{P2} = \frac{1}{2\pi \times R2 \times C12} \quad (14)$$

where

- C14 >> C23 is assumed.

The transfer function for the compensator is calculated as:

$$A(s) = \frac{(1 + s \times C14 \times R2) \times [1 + s \times C12 \times (R1 + R2)]}{s \times R1 \times C14 \times \left[\left(1 + \frac{C23}{C14}\right) + s \times R4 \times C23 \right] \times (1 + s \times R2 \times C12)} \quad (15)$$

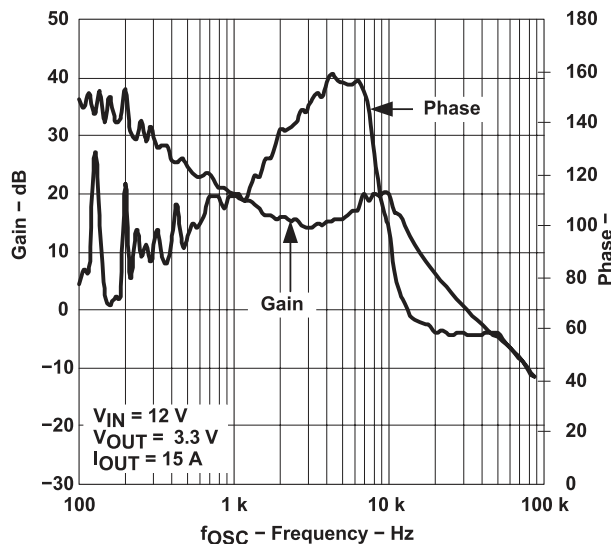


Figure 4-3. Gain and Phase vs Oscillator Frequency (Channel 1)

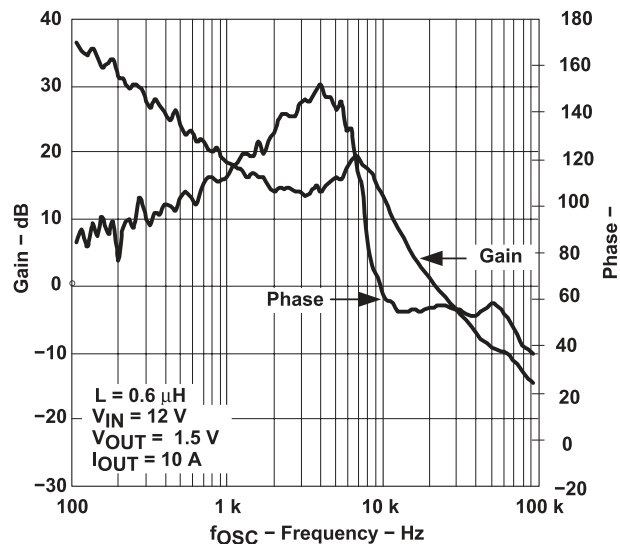


Figure 4-4. Gain and Phase vs Oscillator Frequency (Channel 2)

Figure 4-3 shows the closed loop gain and phase. For Channel 1, the overall crossover frequency is approximately 30 kHz and the phase margin is 58°. For Channel 2, the crossover frequency is approximately 23 kHz and phase margin is 55°.

4.6 Current Limiting

The current limit in the TPS5124 is set using an internal current source and an external resistor (R13 and R14). The current limit protection circuit compares the drain-to-source voltage of the high-side and low-side drivers with respect to the set-point voltage. If the voltage exceeds the limit during high-side conduction, the current limit circuit terminates the high-side driver pulse. If the set point voltage is exceeded during low-side conduction, the low-side pulse is extended through the next cycle. Together, this action has the effect of decreasing the output voltage until the undervoltage protection circuit is activated and the fault latch is set and both the high-side and low-side MOSFET drivers are shut off. Equation 16 should be used for calculating the external resistor value for current protection set point.

$$R_{CL} = \frac{1.3 \times R_{DS(on)} \times \left(I_{LIM} + \frac{I_{RIPPLE}}{2} \right)}{I_{TRIP}} \quad (16)$$

where

- R_{CL} is the external current limit resistor (R13 and R14).
- $R_{DS(on)}$ is the on-resistor of the low-side MOSFET (Q2 and Q4).
- 1.3 is the temperature coefficient of $R_{DS(on)}$.
- I_{LIM} is the required current limit.
- I_{TRIP} is the internal current source with a typical value of 13 μ A at 25°C.

4.7 Timer Latch

The TPS5124 includes fault latch function with a user-adjustable timer to latch the MOSFET drivers in case of a fault condition. When either the OVP or UVP comparator detects a fault condition, the timer starts to charge C18, the external capacitor connected to the SCP pin. The circuit is designed so that for any value of C18, the undervoltage latch time, t_{UVPL} , is about five times larger than the overvoltage latch time t_{OVPL} . The equations needed to calculate the required value of C18 for the desired overvoltage and undervoltage latch delay times are calculated in Equation 17 and Equation 18.

$$C18 = 1.7 \times 10^{-6} \times \frac{t_{UVPL}}{1.185} \quad (17)$$

$$C18 = 8 \times 10^{-6} \times \frac{t_{OVPL}}{1.185} \quad (18)$$

where

- C18 is the external capacitor connected to the SCP pin.
- t_{UVPL} is the time from UVP detection to latch.
- t_{OVPL} is the time from OVP detection to latch.

For the EVM, $t_{UVPL} = 7$ ms and $t_{OVPL} = 1.5$ ms, so $C18 = 0.01$ μ F.

If the voltage on the SCP pin reaches 1.185 V, the fault latch is set, and the MOSFET drivers are set as follows.

4.7.1 Undervoltage Protection

The undervoltage comparator circuit continually monitors the voltage at the INV pin. If the voltage at that pin falls below 78% of the 0.85-V reference, the timer begins to charge C18. If the fault condition persists beyond the time t_{UVPL} , the fault latch is set and both the high-side and low-side drivers is forced OFF.

4.7.2 Short Circuit Protection

The short circuit protection circuitry uses the UVP circuit to latch the MOSFET drivers. When the current limit circuit limits the output current, then the output voltage goes below the target output voltage and UVP comparator detects a fault condition as described above.

4.7.3 Overvoltage Protection

The overvoltage comparator circuit continually monitors the voltage at the INV pin. If V_{INV} rises above 112% of the 0.85-V reference, the timer begins to charge C18. If the fault condition persists beyond the time t_{OVPL} , the fault latch is set and the high-side drivers are forced OFF, while the low-side drivers are forced ON.

CAUTION

Do *not* set the SCP terminal to a voltage lower than 1.185 V while the device is timing out an OVP or UVP event. If the SCP terminal is manually set to a voltage lower than 1.185 V during this time, output overshoot can occur. The TPS5124 must be reset by grounding STBYx.

4.7.4 Disabling the Protection Function

If it is necessary to disable the protection functions of the TPS5124 for troubleshooting or other purposes, the OCP, OVP, and UVP circuits can be disabled.

4.7.4.1 Disabling the Overcurrent Protection

Remove the current limit resistors R13 and R14 to disable the current limit function.

4.7.4.2 Disabling the Overvoltage Protection or Undervoltage Protection

Grounding the SCP terminal can disable OVP and UVP.

5 Test Results

5.1 Efficiency Curves

The efficiency was tested under three different operation conditions.

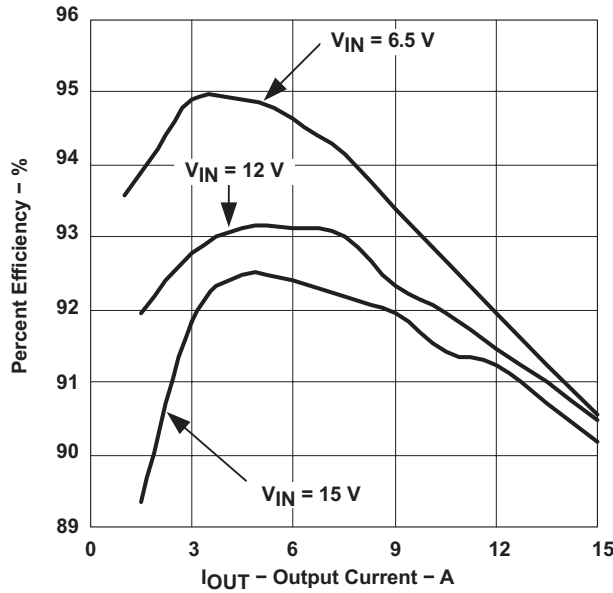


Figure 5-1. Overall Efficiency vs Output Current VOUT1 (3.3 V) Enabled Only

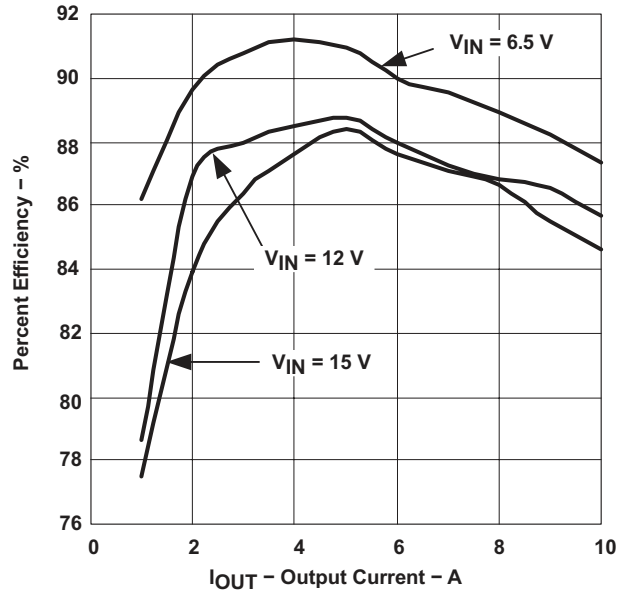


Figure 5-2. Overall Efficiency vs Output Current VOUT1 (1.5 V) Enabled Only

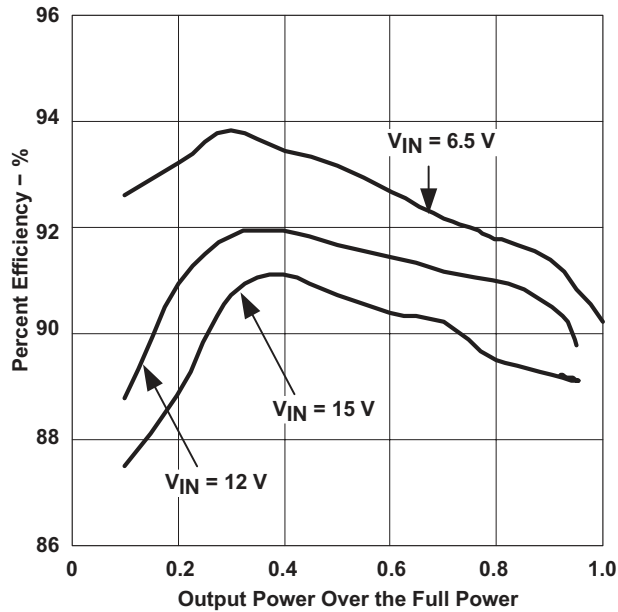


Figure 5-3. Overall Efficiency vs Output Power with Both Channels Enabled

5.2 Typical Operating Waveform

Figure 5-4 shows the typical operating waveforms taken at $V_{IN} = 12\text{ V}$, $I_{OUT1} = 15\text{ A}$, and $I_{OUT2} = 10\text{ A}$.

5.3 Start-Up Waveform

Figure 5-5 shows the start-up waveform taken at $V_{IN} = 12\text{ V}$, $I_{OUT1} = 15\text{ A}$, and $I_{OUT2} = 10\text{ A}$. The rising time is 2.85 ms for V_{OUT1} and 2.12 ms for V_{OUT2} .

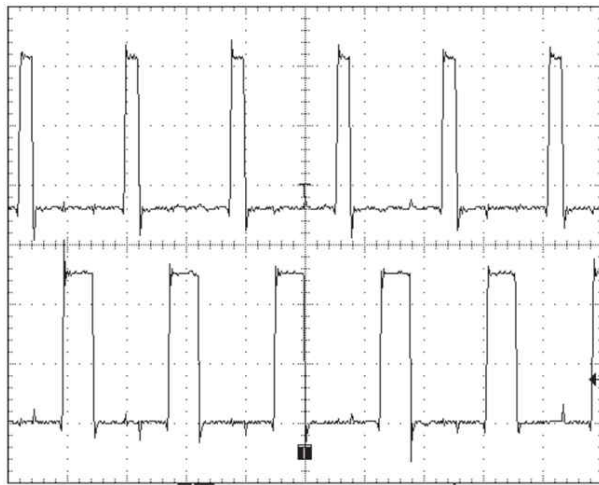
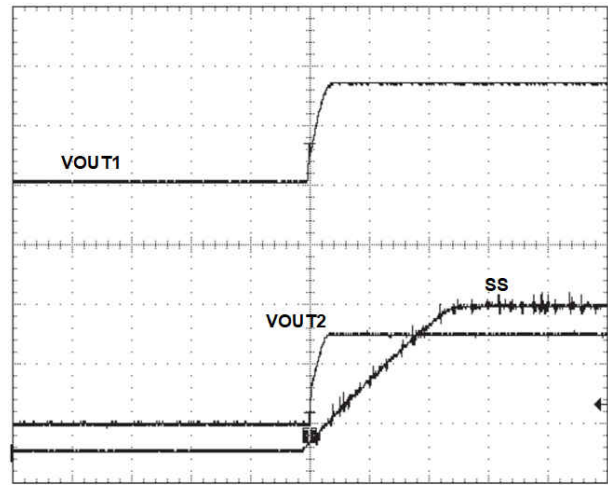

 t - Time - 2 μ s/div

Figure 5-4. Switch Node Waveform


t - Time - 10 ms/div

Figure 5-5. Start-Up Waveform

5.4 Output Ripple Voltage and Load Transient

The output ripple is about 20 mV_{P-P} at 15 A on Channel 1 (3.3 V) output and 15 mV_{P-P} at 10 A on Channel 2 output as shown in [Figure 5-6](#).

[Figure 5-7](#) shows the load transient response. For Channel 1 (3.3 V), when the load steps from 0 A to 8.5 A, the overshoot and undershoot voltages are about 150 mV. For Channel 2 (1.5 V), when the load steps from 0 A to 7.5 A, the overshoot voltage is approximately 220 mV and the undershoot voltage is approximately 140 mV.

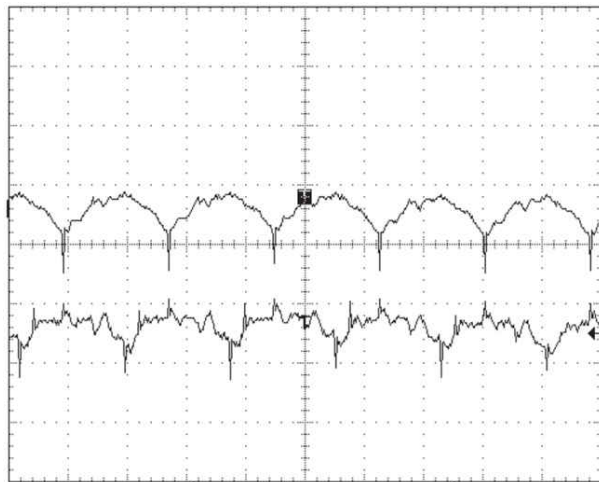

 t - Time - 2 μ s/div

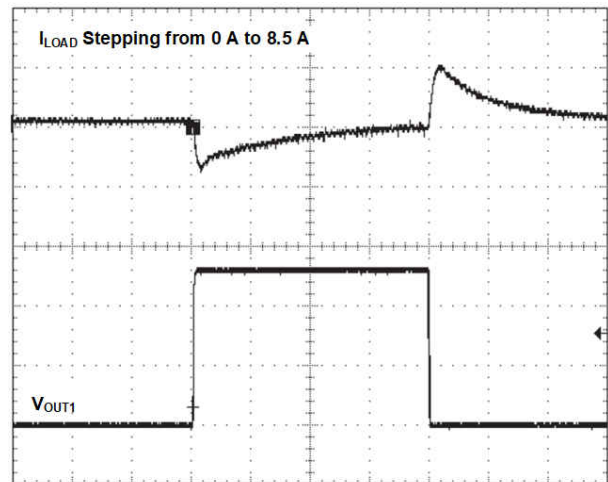
Figure 5-6. Output Ripple

 t - Time - 40 μ s/div

Figure 5-7. Load Transient Response

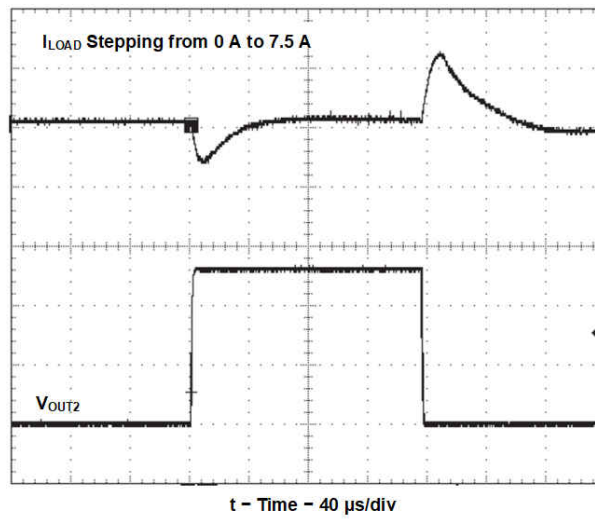


Figure 5-8. Load Transient Response

6 Layout Guidelines

Proper design and layout is crucial to the performance of the power supply. Here are some suggestions to the layout of TPS5124 design:

- A four-layer PCB design is recommended for designs using the TPS5124. Use at least one layer dedicated to the PWRGND plane.
- All sensitive analog components such as INV, REF, CT, GND, SCP, and SOFTSTART should be reference to ANAGND.
- Ideally, all area directly under the TPS5124 chip should also be ANAGND.
- GND and PWRGND should be isolated as much as possible, with a single point connection between them.

6.1 Low-Side MOSFET

- The source of the low-side MOSFETs should be referenced with PWRGND. Otherwise, ANAGND is subject to the noise of the outputs.
- PWRGND should be placed closed to the source of the low-side MOSFETs.

6.2 Connections

- Connections from the drivers to the gate of the power MOSFETs should be as short and wide as possible to reduce stray inductance. This becomes more critical if external gate resistors are not used. In addition, an external gate resistor for the high-side FETs will considerably reduce the noise at the LL node and improve the performance of the current limit function.
- The connection from LL to the power MOSFETs should be as short and wide as possible.

6.3 Bypass Capacitor

- The bypass capacitor for VCC should be placed close to the TPS5124.
- The bulk storage capacitors across VCC should be placed close to the power MOSFETs. High-frequency bypass capacitors should be placed in parallel with the bulk capacitors and connected close to the drain of the high-side MOSFETs and to the source of the low-side MOSFETs.
- For noise reduction, a 0.1- μ F capacitor, C_{TRIP} , should be placed in parallel with the trip resistor RCL.

6.4 Bootstrap Capacitor

- The bootstrap capacitor C_{BS} (connected from LH to LL) should be placed close to the TPS5124.
- LH and LL should be routed close to each other to minimize noise coupling to these traces.
- LH and LL should not be routed near the control pin area (for example, INV, FB, REF, and so forth).

6.5 Output Voltage

- The output voltage sensing trace should be isolated by either ground plane.
- The output voltage sensing trace should not be placed under the inductors on the same layer.
- The feedback components should be isolated from output components, such as, MOSFETs, inductors, and output capacitors. Otherwise the feedback signal line is susceptible to output noise.
- The resistors to set up the output voltage should be referenced to ANAGND.
- The INV trace should be as short as possible.

7 PCB Layout

Figure 7-1 through Figure 7-5 shows the PCB layout.

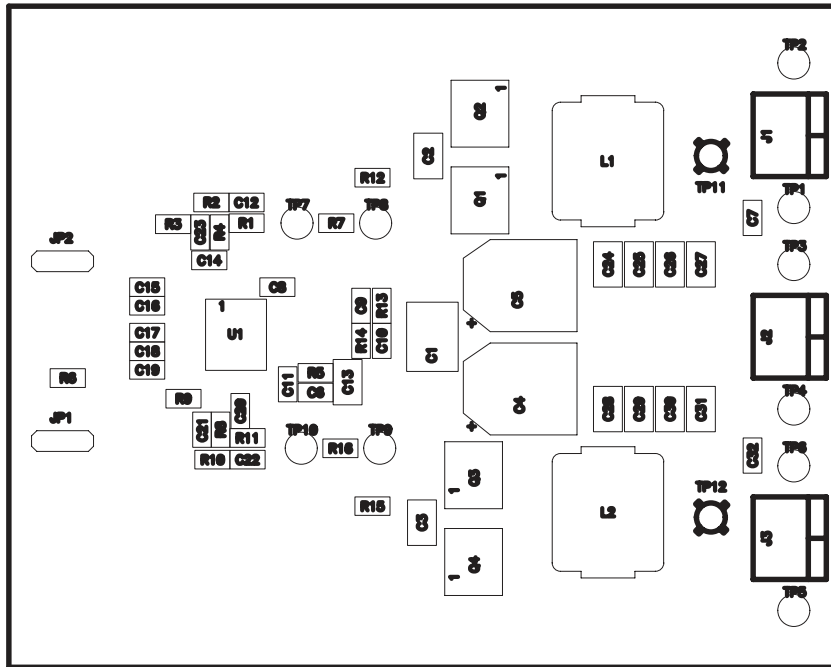


Figure 7-1. Top Assembly

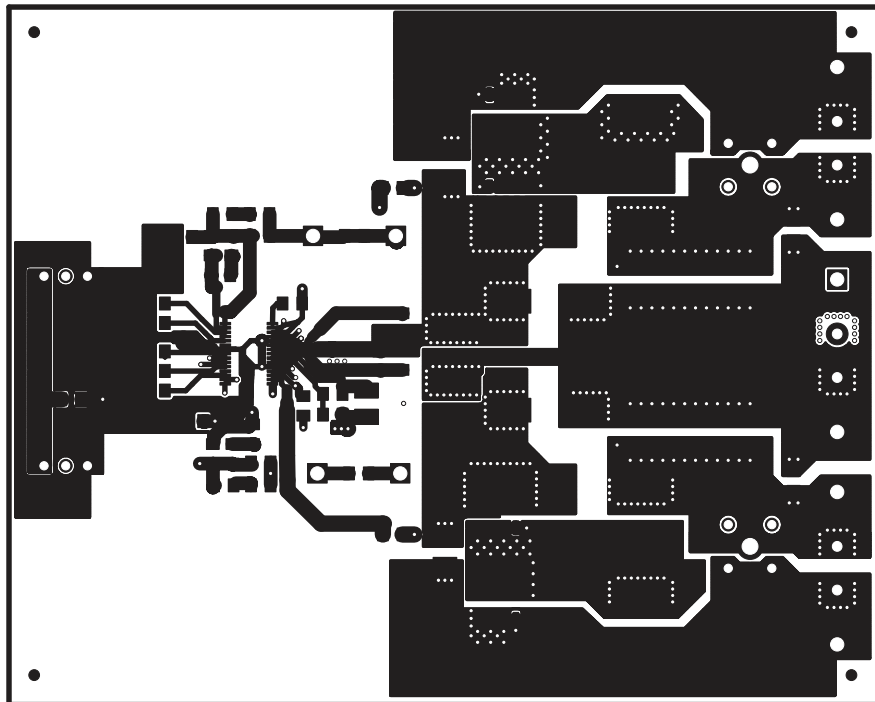


Figure 7-2. Top Side

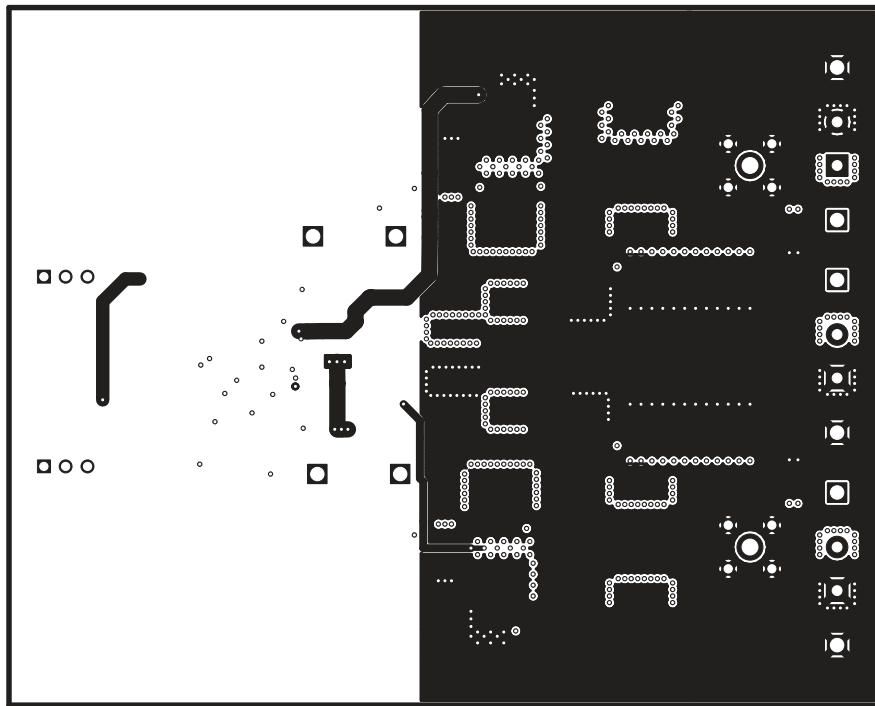


Figure 7-3. Internal 1

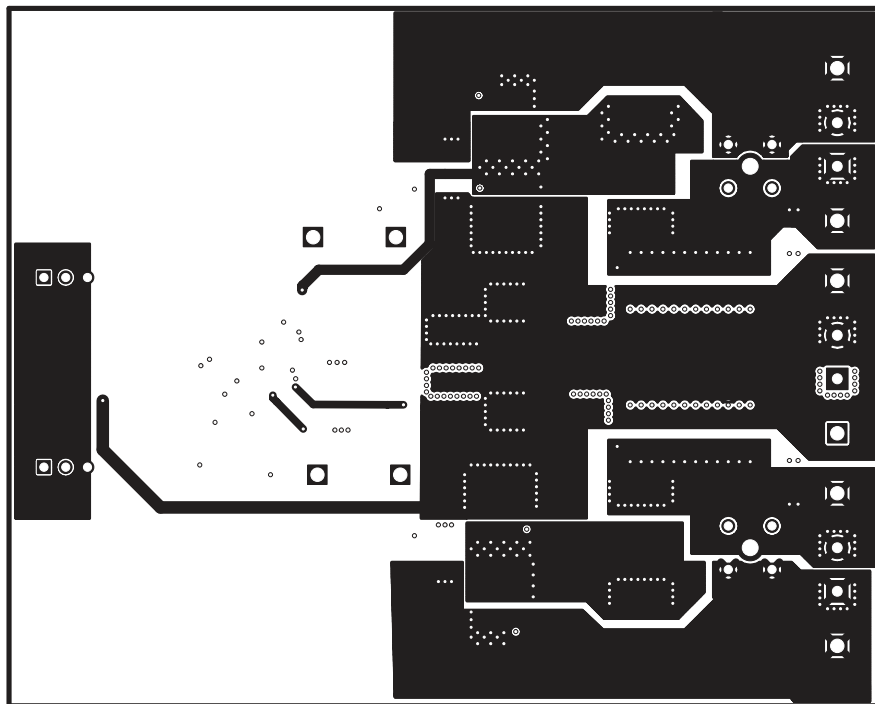


Figure 7-4. Internal 2

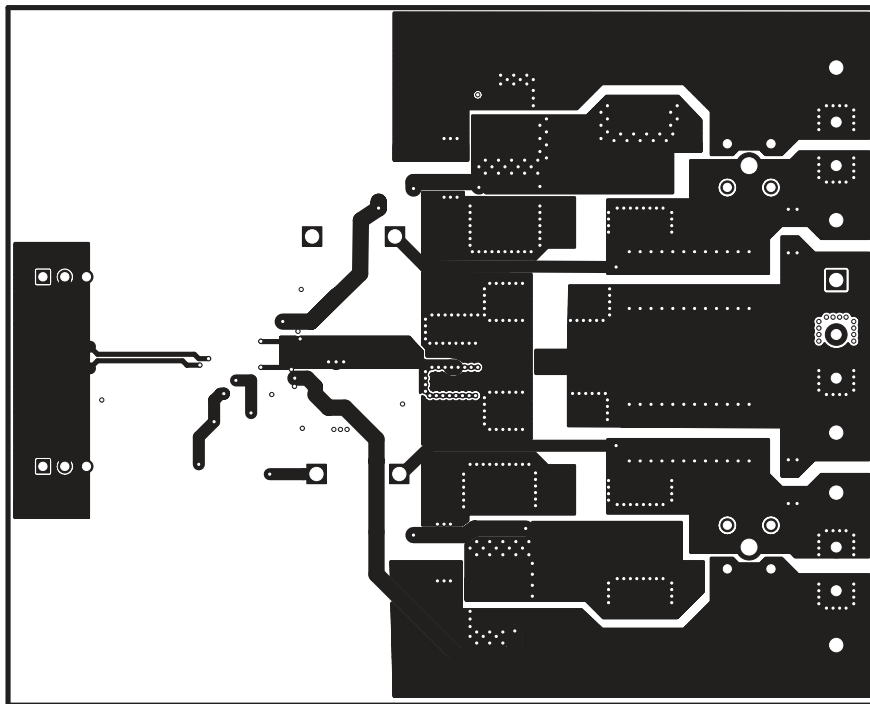


Figure 7-5. Bottom Side

8 List of Materials

Table 8-1. List of Materials

REFERENCE DESIGNATOR	QTY	DESCRIPTION	SIZE	MFR	PARTNUMBER
C1–C3	3	Capacitor, ceramic, 2.2 μ F, 50 V, X7R, 10%	1210	Std	Std
C12, C22	2	Capacitor, ceramic, 5600 pF, 50 V, X7R, 10%	805	Std	Std
C13	1	Capacitor, ceramic, 10 μ F, 10 V, X5R, 10%	1210	Murata	GRM32ER61A106KC01L
C14, C20	2	Capacitor, ceramic, 0.027 μ F, 50 V, X7R, 10%	805	Std	Std
C7, C15, C18, C19, C32	5	Capacitor, ceramic, 0.01 μ F, 50 V, X7R, 10%	805	Std	Std
C16	1	Capacitor, ceramic, 47 pF, 50 V, COG, 5%	805	Std	Std
C21, C23	2	Capacitor, ceramic, 1000 pF, 50 V, COG, 5%	805	Std	Std
C24–C31	8	Capacitor, ceramic, 100 μ F, 6.3 V, X5R	1210	TDK	C3225X5R0J107M
C4, C5	2	Capacitor, special polymer, 150 μ F, 20, 20%	10.3 mm (F12)	Panasonic	EEFWA1D151P
C6, C8–C11, C17	6	Capacitor, ceramic, 0.1 μ F, 50 V, X7R, 10%	805	Std	Std
J1, J2, J3	3	Terminal block, 2 pin, 15 A, 5.1 mm	0.40 × 0.35	OST	ED1609
JP1, JP2	2	Header, 3-pin, 100-mil spacing (36-pin strip)	0.100 × 3	Sullins	PTC36SAAN
L1, L2	2	Inductor, SMT, 2.2 μ H, 20 A, 4.6 m Ω	0.51 × 0.51	Vishay–Sili conix	IHLP5050EZ–01
Q1, Q3	2	MOSFET, N-channel, 30 V, 18 A, 8.0 m Ω	PWRPAKS 0–8	Vishay–Sili conix	Si7860DP
Q2, Q4	2	MOSFET, N-channel, 30 V, 29 A, 3 m Ω	PWRPAKS 0–8	Vishay–Sili conix	Si7880DP
R1, R11	2	Resistor, chip, 10.0 kW, 1/10 W, 1%	805	Std	Std
R10	1	Resistor, chip, 68.1 W, 1/10 W, 1%	805	Std	Std
R5	1	Resistor, chip, 10.0 W, 1/10 W, 1%	805	Std	Std
R12, R15	2	Resistor, chip, 1.5 W, 1/10 W, 1%	805	Std	Std
R13	1	Resistor, chip, 20.0 kW, 1/10 W, 1%	805	Std	Std
R14	1	Resistor, chip, 14.0 kW, 1/10 W, 1%	805	Std	Std
R16, R7	2	Resistor, chip, 49.9 W, 1/10 W, 1%	805	Std	Std
R2	1	Resistor, chip, 14 W, 1/10 W, 1%	805	Std	Std
R3	1	Resistor, chip, 3.48 kW, 1/10 W, 1%	805	Std	Std
R4, R8	2	Resistor, chip, 1.10 kW, 1/10 W, 1%	805	Std	Std
R6	1	Resistor, chip, 100 kW, 1/10 W, 1%	805	Std	Std
R9	1	Resistor, chip, 13.0 kW, 1/10 W, 1%	805	Std	Std
TP1–TP10	10	Test point, 0.062 hole	0.25	Keystone	5012
TP11, TP12	2	Adaptor, 3.5-mm probe clip (or 131–5031–00)	0.2	Tektronix	131–4244–00
U1	1	IC, dual-channel synchronous step-down PWM controller	DBT30	TI	TPS5124DBT
	1	PCB, 4 in × 3.2 in × .062 in		Any	HPA053

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision * (January 2004) to Revision A (March 2022)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document.	2
• Updated the user's guide title.....	2

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